

STA3350F

PNP Silicon Transistor

Applications

- Power amplifier application
- High current switching application

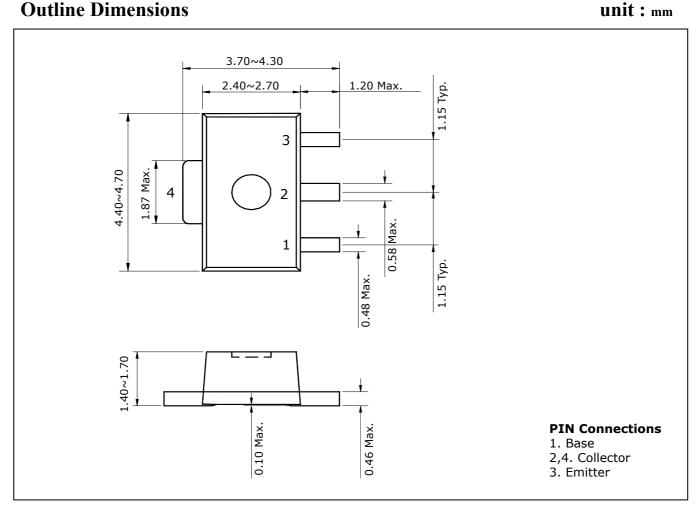
Features

- Low saturation voltage: $V_{\text{CE(sat)}}$ =-0.15V Typ. @ I_{C} =-1A, I_{B} =-50mA
- Large collector current capacity: I_C=-3A
- Small and compact SMD type package
- Complementary pair with STC4350F

Ordering Information

Type NO.	Marking	Package Code		
STA3350F	HW7	SOT-89		

Outline Dimensions



KSD-T5B006-000

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Absolute Maximum Ratings

[Ta=25°C]

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-6	V
Collector current	I_{C}	-3	А
Collector Dower dissipation	P _C	0.5	W
Collector Power dissipation	P _C *	1	W
Junction temperature	T ₁	150	°C
Storage temperature range	T _{stg}	-55~150	°C

[▼] Device mounted on ceramic substrate (250mm² x 0.8t)

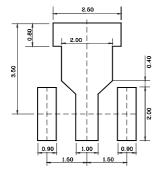
Electrical Characteristics

[Ta=25℃]

Chara	cteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage		BV _{CEO}	I_C =-1mA, I_B =0	-50	-	-	V
Collector cut-off of	current	I_{CBO}	V _{CB} =-50V, I _E =0	-	-	-1	μА
Emitter cut-off cu	rrent	I_{EBO}	V_{EB} =-6V, I_C =0	-	-	-1	μΑ
DC current gain		h _{FE}	V _{CE} =-2V, I _C =-0.5A*	120	-	240	
		h _{FE}	V _{CE} =-2V, I _C =-2A*	40	-	-	
Collector-emitter	saturation voltage	$V_{CE(sat)}$	I _C =-1A, I _B =-0.05A*	-	-	-0.35	V
Base-emitter saturation voltage		$V_{BE(sat)}$	I _C =-2A, I _B =-0.1A*	-	-0.97	-1.2	V
Transition frequency		f _T	V _{CE} =-10V, I _C =-0.05A	-	250	-	MHz
Collector output capacitance		C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz	-	28	-	pF
Switching Time	Turn-on Time	t _{on}	Ise INPUT Ise OUTPUT	-	100	-	
	Storage Time	t _{stg}		-	300	-	ns
	Fall Time	t _f		-	50	-	

^{*:} Pulse test : $t_P \le 300 \mu s$, Duty cycle $\le 2\%$

* Recommend PCB solder land [Unit: mm]



Electrical Characteristic Curves

Fig. 1 $P_{\rm C}~$ - T_a

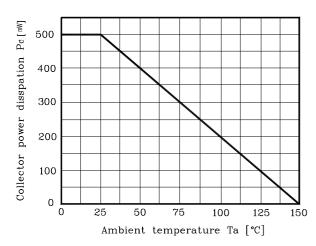


Fig. 2 $I_{C}\;$ - V_{BE}

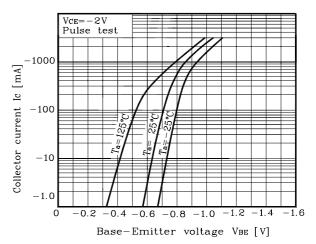


Fig. 3 $I_{C}\;$ - V_{CE}

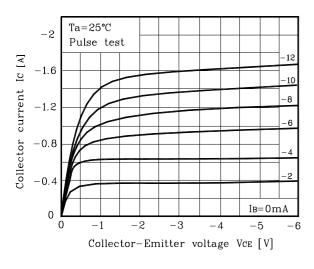


Fig. 4 h_{FE} - I_C

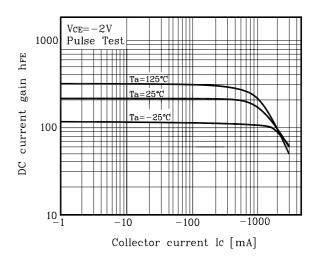


Fig. 5 $V_{\text{CE(sat)}}$ - I_{C}

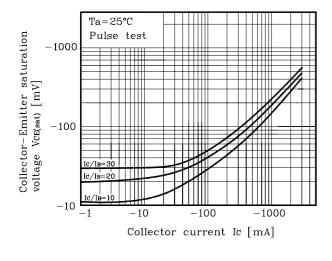
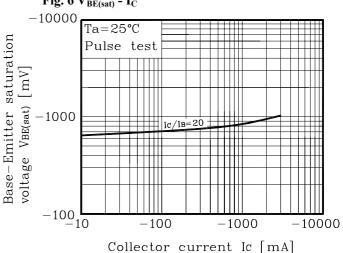
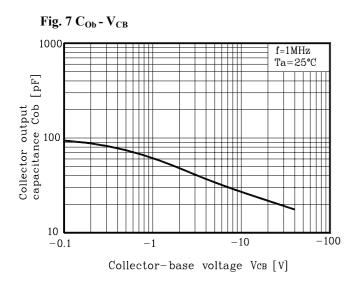


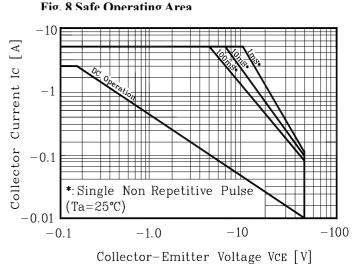
Fig. 6 $V_{BE(sat)}$ - I_{C}



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Electrical Characteristic Curves





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